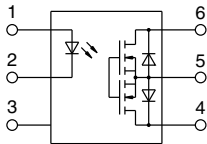
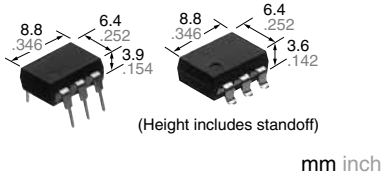




Capable of 2A to 3A high-frequency load switching	PhotoMOS® HE 1 Form A High Capacity (AQV251G, AQV252G)
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RoHS compliant

FEATURES

- 1. Greatly increased load current in a compact DIP package**
Continuous load current: 3.5A (AQV251G)
- 2. Greatly improved specifications allow you to use this in place of mercury and mechanical relays.**
- 3. Low on-resistance (Typ. 35mΩ, AQV251G)**

TYPICAL APPLICATIONS

- **Measuring instrument market** (Testers etc.)
- **Industrial machinery and equipment**
- **Power supply controls**
- **Security/Disaster prevention market** I/O sections of warning devices, security systems, etc.

TYPES

	Output rating*		Package	Part No.				Packing quantity	
				Through hole terminal	Surface-mount terminal			Tube	Tape and reel
	Load voltage	Load current			Tube packing style	Tape and reel packing style			
					Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side			
AC/DC dual use	30 V	3.5 A	DIP6-pin	AQV251G	AQV251GA	AQV251GAX	AQV251GAZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.
	60 V	2.5 A	DIP6-pin	AQV252G	AQV252GA	AQV252GAX	AQV252GAZ		

*Indicate the peak AC and DC values.
Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

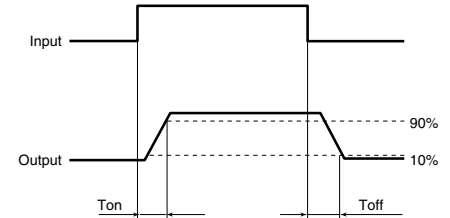
Item		Symbol	Type of connection	AQV251G(A)	AQV252G(A)	Remarks
Input	LED forward current	I _F	/	50 mA		
	LED reverse voltage	V _R		5 V		
	Peak forward current	I _{FP}		1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}		75 mW		
Output	Load voltage (peak AC)	V _L		30 V	60 V	
	Continuous load current	I _L	A	3.5 A	2.5 A	A connection: Peak AC, DC B, C connection: DC
			B	4.0 A	3.5 A	
			C	6.0 A	5.0 A	
	Peak load current	I _{peak}		6.0 A		100ms (1 shot), V _L = DC
Power dissipation	P _{out}		600 mW			
Total power dissipation		P _T		650 mW		
I/O isolation voltage		V _{iso}		1,500 Vrms		
Ambient temperature	Operating	T _{opr}		-40 to +85°C -40 to +185°F		(Non-icing at low temperatures)
	Storage	T _{stg}		-40 to +100°C -40 to +212°F		

HE 1 Form A High Capacity (AQV251G, AQV252G)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV251G(A)	AQV252G(A)	Condition	
Input	LED operate current	Typical	I _{Fon}	0.55 mA	0.5 mA	I _L = 100mA	
		Maximum					
	LED turn off current	Minimum	I _{Foff}	3 mA		I _L = 100mA	
Typical		0.2 mA					
LED dropout voltage	Typical	V _F	—	1.14 V (1.32 V at I _F = 50 mA)		I _F = 5 mA	
	Maximum			1.5 V			
Output	On resistance	Typical	R _{on}	A	0.035 Ω	0.08 Ω	I _F = 5 mA I _L = Max. Within 1 s
		Maximum			0.08 Ω	0.12 Ω	
	Typical	R _{on}	B	0.018 Ω	0.04 Ω		
	Maximum			0.04 Ω	0.06 Ω		
	Typical	R _{on}	C	0.01 Ω	0.02 Ω		
	Maximum			0.02 Ω	0.03 Ω		
Off state leakage current	Maximum	I _{Leak}	—	1 μA		I _F = 0 mA, V _L = Max.	
Transfer characteristics	Turn on time*	Typical	T _{on}	—	1.1 ms		I _F = 5 mA, I _L = 100 mA V _L = 10 V
		Maximum			5.0 ms		
	Turn off time*	Typical	T _{off}	—	0.1 ms	0.25 ms	I _F = 5 mA, I _L = 100 mA V _L = 10 V
		Maximum			0.5 ms		
	I/O capacitance	Typical	C _{iso}	—	0.8 pF		f = 1 MHz V _B = 0 V
		Maximum			1.5 pF		
Initial I/O isolation resistance	Minimum	R _{iso}	—	1,000 MΩ		500 V DC	
Max. operating frequency	Maximum	—	—	10 cps	—	I _F = 5 mA, duty = 50% V _L × I _L = 100 V·A	

*Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item		Symbol	Min.	Max.	Unit
LED current		I _F	5	30	mA
AQV251G(A)	Load voltage (Peak AC)	V _L	—	24	V
	Continuous load current (A connection)	I _L	—	3.5	A
AQV252G(A)	Load voltage (Peak AC)	V _L	—	48	V
	Continuous load current (A connection)	I _L	—	2.5	A

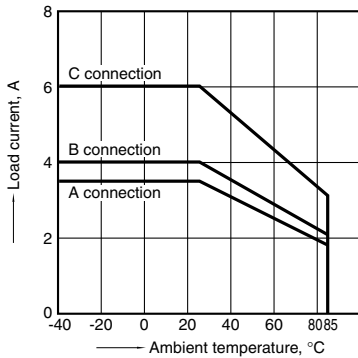
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

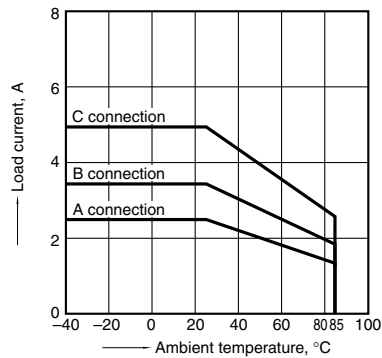
1.-(1) Load current vs. ambient temperature characteristics

Tested sample: AQV251G;
Allowable ambient temperature: -40 to +85°C
-40 to +185°F



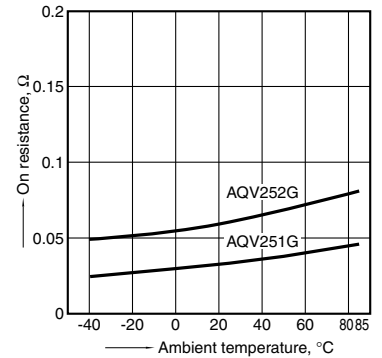
1.-(2) Load current vs. ambient temperature characteristics

Tested sample: AQV252G;
Allowable ambient temperature: -40 to +85°C
-40 to +185°F



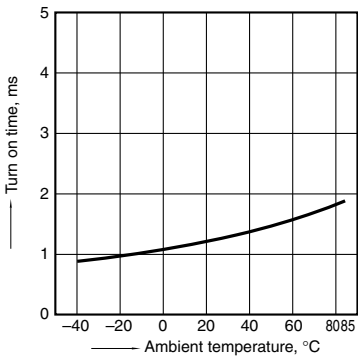
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Load voltage: Max. (DC)
Continuous load current: Max. (DC)



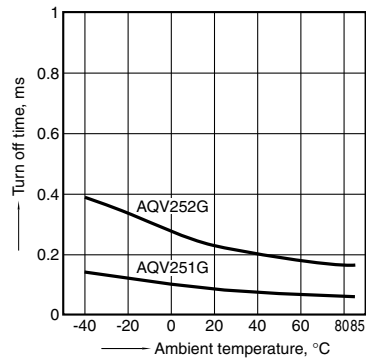
3. Turn on time vs. ambient temperature characteristics

Tested sample: All; LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



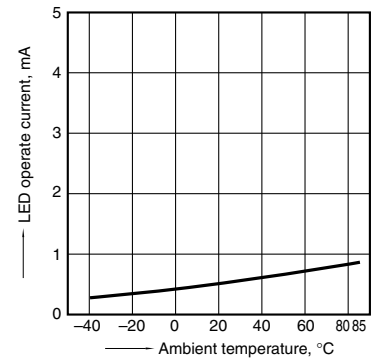
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



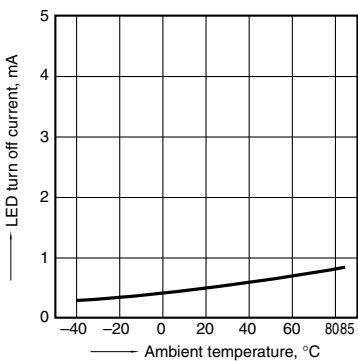
5. LED operate current vs. ambient temperature characteristics

Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



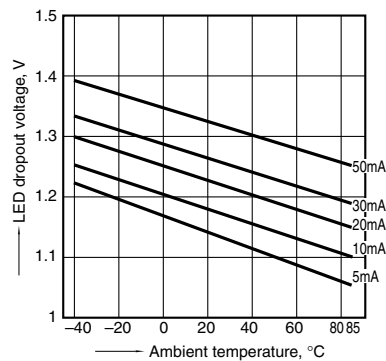
6. LED turn off current vs. ambient temperature characteristics

Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



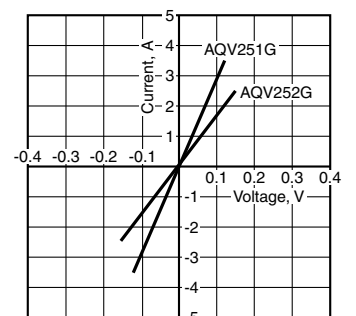
7. LED dropout voltage vs. ambient temperature characteristics

Tested sample: All;
LED current: 5 to 50 mA



8. Current vs. voltage characteristics of output at MOS portion

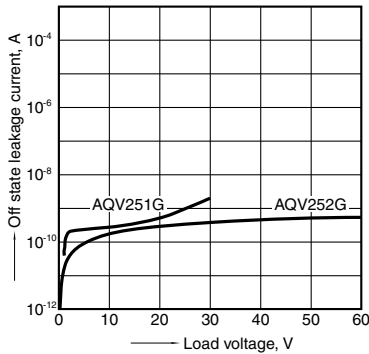
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



HE 1 Form A High Capacity (AQV251G, AQV252G)

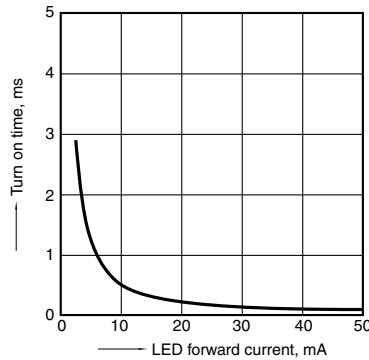
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



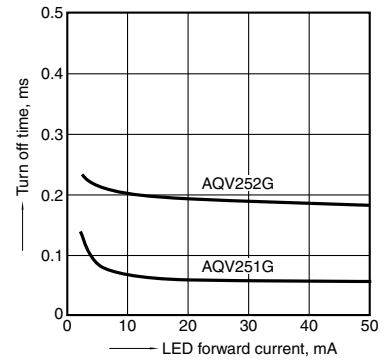
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Tested sample: All; Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



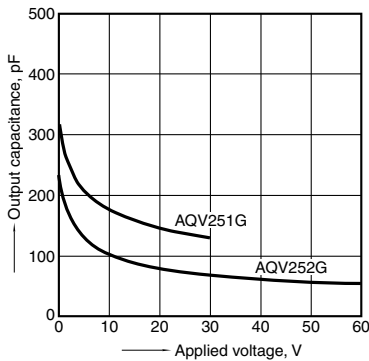
11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



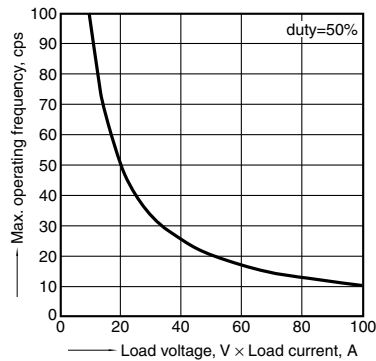
12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F



13. Max. operating frequency vs. load voltage and current characteristics

Tested sample: AQV251G;
LED current: 5 mA;
Ambient temperature: 25°C 77°F



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